

2-Bit Bidirectional Voltage-Level Translator with Auto Direction Sensing and ±15kV ESD Protection UM3302H CSP8 1.90×0.90 UM3302M8 MSOP8

General Description

The UM3302, an ESD protected level translator, provides the level shifting necessary to allow data transfer in multi-voltage system. This 2-channel non-inverting translator uses two separate configurable power-supply rails. The A port is designed to track V_{CCA} . V_{CCA} accepts any supply voltage from 1.2V to 3.6V. The B port is designed to track V_{CCB} . V_{CCB} accepts any supply voltage from 1.65V to 5.5V. This allows for universal low-voltage bidirectional translation between any of the 1.2V, 1.5V, 1.8V, 2.5V, 3.3V, and 5V voltage nodes. Both I/O ports are auto-sensing; thus, no direction pin is required, making it ideal for data transfer between low-voltage ASICs/PLDs and higher voltage systems.

The UM3302 operates at a guaranteed data rate of 20Mbps over the entire specified operating voltage range. Within specific voltage domains, higher data rates are up to 100Mbps.

When the output-enable (OE) input is low, all outputs are placed in the high-impedance state. The UM3302 is designed so that the OE input circuit is designed to track V_{CCA} .

To ensure the high-impedance state during power up or power down, OE should be tied to GND through a pull down resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

The UM3302H is a dual channel level translator available in 1.90mm×0.90mm CSP8 bump package while the UM3302M8 is available in MSOP8 package.

Applications

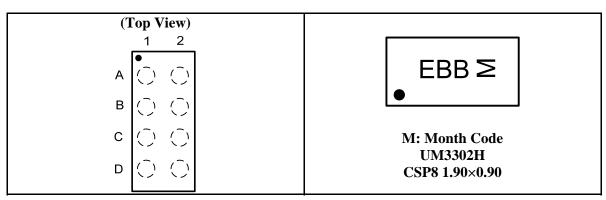
Features

- Low-Voltage ASIC Level Translation
- Cell-Phone Cradles
- Portable POS Systems
- Portable Communication Devices
- Low-Cost Serial Interfaces
- Cell-Phones
- GPS
- Telecommunications Equipment

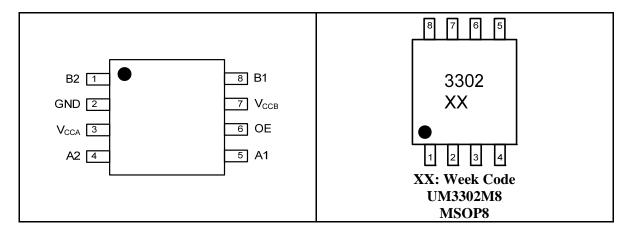
Pin Configurations

- 1.2V to 3.6V on A Port and 1.65V to 5.5V on B Port ($V_{CCA} \leq V_{CCB}$)
- V_{CC} Isolation Feature If Either V_{CC} Input is at GND, All Outputs are in the High-Impedance State
- OE Input Circuit Referenced to V_{CCA}
- Low Power Consumption
- Latch-Up Performance Exceeds 100mA
- ± 15 kV ESD Protection on B Ports

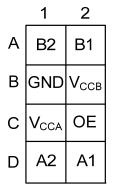
Top View







Ball Mapping for UM3302H



Transparent Top View

Pin Description

Pin	No	D ' N	Error di an
UM3302H	UM3302M8	Pin Name	Function
A1	1	B2	Input/Output B. Referenced to V _{CCB}
B1	2	GND	Ground
C1	3	V _{CCA}	A-Port Supply Voltage. 1.2V \leq V _{CCA} \leq 3.6V and V _{CCA} \leq V _{CCB}
D1	4	A2	Input/Output A. Referenced to V _{CCA}
D2	5	A1	Input/Output A. Referenced to V _{CCA}
C2	6	OE	3-State Output Enable. Pull OE low to place all outputs in 3-state mode. Referenced to V_{CCA}
B2	7	V _{CCB}	B-Port Supply Voltage. 1.65V ≤ V _{CCB} ≤ 5.5V
A2	8	B1	Input/Output B. Referenced to V _{CCB}

Ordering Information

Part Number	Packaging Type	Marking Code	Shipping Qty
UM3302H	CSP8 1.90×0.90	EBB	3000pcs/7Inch Tape & Reel
UM3302M8	MSOP8	3302	3000pcs/13Inch Tape & Reel



Absolute Maximum Ratings (Note 1)

Over operating free-air temperature range (unless otherwise noted)

Symbol	Parameter		Value	Unit
V _{CCA}	Supply Voltage Range		-0.5 to +4.5	V
V _{CCB}	Supply Voltage Range		-0.5 to +6.5	V
V	Input Voltage Range (Note 2)	A Port	-0.5 to +4.5	v
V_{I}	input voltage Range (Note 2)	B Port	-0.5 to +6.5	v
Vo	Voltage Range Applied to Any Output in the High-Impedance or	A Port	-0.5 to +4.5	V
v _O	Power-Off State (Note 2)	B Port	-0.5 to +6.5	v
V	Voltage Range Applied to Any Output in the High or Low State	A Port	-0.5 to (V_{CCA} +0.5)	V
Vo	(Note 2, 3)	B Port	-0.5 to $(V_{CCB}+0.5)$	v
I _{IK}	Input Clamp Current	$V_{I} \leq 0$	-50	mA
I _{OK}	Output Clamp Current	V ₀ <0	-50	mA
Io	Continuous Output Current		±50	mA
	Continuous Current through V _{CCA} ,	V _{CCB} , or GND	±100	mA
T _{OP}	Operating Temperature Range		-40 to +85	°C
T _{STG}	Storage Temperature Range		-65 to +150	°C

- Note 1: Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- Note 2: The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.
- Note 3: The value of V_{CCA} and V_{CCB} are provided in the recommended operating conditions table.

Recommended Operating Conditions (Note 1, 2)

Symbol	Parameter	r	V _{CCA}	V _{CCB}	Min	Max	Unit
V _{CCA}	Supply Valte				1.2	3.6	V
V _{CCB}	Supply Volta	ige			1.65	5.5	V
V	High Level Input	Data Inputs	1.2V to 3.6V	1.65V to 5.5V	$V_{CCI} \times 0.65^{(Not}$	ote ³⁾ V _{CCI}	V
V_{IH}	Voltage	OE Input	1.2V to 3.6V	1.65V to 5.5V	$V_{CCA} \times 0.65$	5.5	V
V	Low Level Input	Data Inputs	1.2V to 3.6V	1.65V to 5.5V	0 V ₀	_{CCI} ×0.35	V
V_{IL}	Voltage	OE Input	1.2V to 3.6V	1.65V to 5.5V	0 V ₀	_{CCA} ×0.35	V
V	Voltage Range Applied to Any Output in the	A Port	1.2V to 3.6V	1.65V to 5.5V	0	3.6	v
V _O	High-Impedance or Power Off State	B Port	1.2 v to 3.0 v	1.05 V to 5.5 V	0	5.5	v
	Innut Transition	A-Port Inputs	1.2V to 3.6V	1.65V to 5.5V		40	
$\Delta t/\Delta V$	Input Transition Rise or Fall Time	B-Port Inputs	1.2V to 3.6V	1.65V to 1.95V		40	ns/V
	Rise of 1 all Thile	B-1 of t inputs	1.2 v to 3.0 v	4.5V to 5.5V		30	

Note 1. The A and B sides of an unused data I/O pair must be held in the same state, i.e., both at V_{CCI} or both at GND.

Note 2. V_{CCA} must be less than or equal to V_{CCB} and must not exceed 3.6 V.

Note 3. V_{CCI} is the supply voltage associated with the input port.



Electrical Characteristics (Note 1, 2)

Over recommended operating free-air temperature range (unless otherwise noted)

D		Test	X 7	N7	T _A =	25°C	-40°C t	to 85° C	TI*4
Par	rameter	Conditions	V _{CCA}	V _{CCB}	Min	Max	Min	Max	Unit
	V _{OHA}	I _{он} =-20µА	1.2V		1.1				v
	V OHA	1 _{0H} 20μΑ	1.4V to 3.6V				V _{CCA} -0	.4	v
	V _{OLA}	I _{OL} =20μA	1.2V		0.9		v		
	V OLA	1 _{0L} -20μΑ	1.4V to 3.6V					0.4	v
	V _{OHB}	I _{OH} =-20μA		1.65V to 5.5V			V _{CCB} -0	.4	V
,	V _{OLB}	I _{OL} =20μA		1.65V to 5.5V				0.4	V
I_{I}	OE	V _I =V _{CCI} or GND	1.2V to 3.6V	1.65V to 5.5V		± 1		±2	μΑ
т	A Port	V_{I} or $V_{O}=0$ to 3.6V	0V	0V to 5.5V		±1		±2	
I _{off}	B Port	$V_{\rm I}$ or $V_{\rm O}=0$ to 5.5V	0V to 3.6V	0V		±1		±2	μA
I _{OZ}	A or B Port	OE=GND	1.2V to 3.6V	1.65V to 5.5V		±1		±2	μΑ
			1.2V	1.65V to 5.5V	0.06				
		$V_{I} = V_{CCI}$ or	1.4V to 3.6V	1.65V to 5.5V				3	
	I _{CCA}	GND, I _O =0	3.6V	0V				2	μA
			0V	5.5V				-2	
			1.2V	1.65V to 5.5V	3.4				
	T	V _I =V _{CCI} or	1.4V to 3.6V	1.65V to 5.5V				5	
	I _{CCB}	GND, I _O =0	3.6V	0V				-2	μA
			0V	5.5V				2	1
т	1 T	V _I =V _{CCI} or	1.2V	1.65V to 5.5V	3.5				
ICC	_{CA} +I _{CCB}	GND, I _O =0	1.4V to 3.6V	1.65V to 5.5V				8	μA
	r	V _I =V _{CCI} or GND,	1.2V	1.65V to 5.5V	0.05				
1	I _{CCZA}	I _O =0, OE=GND	1.4V to 3.6V	1.65V to 5.5V	3		μA		
	r	V _I =V _{CCI} or GND,	1.2V	1.65V to 5.5V	3.3				
	I _{CCZB}	I _O =0, OE=GND	1.4V to 3.6V	1.65V to 5.5V				5	μA
Ci	OE		1.2V to 3.6V	1.65V to 5.5V	2.5			3	pF
C	A Port		1 3 V to 2 6 V	1 6511 40 5 537	5 6		6	"F	
C _{iO}	B Port		1.2V to 3.6V	1.65V to 5.5V	11			14	pF

Note 1. V_{CCI} is the supply voltage associated with the input port. Note 2. V_{CCO} is the supply voltage associated with the output port.



Switching Characteristics T_A =+25°C, V_{CCA} =1.2V

Donomotor	From	То	V _{CCB} =1.8V	$V_{CCB}=2.5V$	$V_{CCB}=3.3V$	V _{CCB} =5V	Unit
Parameter	(Input)	(Output)	Тур	Тур	Тур	Тур	Unit
+	А	В	7	6	5.3	5.5	
t _{pd}	В	А	7.5	6.5	6	6	ns
+	OE	А	1	1	1	1	
t _{en}	UE	В	1	1	1	1	μs
+	OE	А	18	16	14	14	na
t _{dis}	UE	В	19	17	15	15	ns
$t_{rA,} t_{fA}$		se and Fall me	5	5	5	5	ns
$t_{rB,} t_{fB}$		se and Fall me	2.5	1.5	1.2	1	ns
t _{SK(O)}	Channel-t	o-Channel	0.5	0.5	0.5	1.5	ns
Max Data Rate			20	20	20	20	Mbps

Switching Characteristics

Over recommended operating free-air temperature range, $V_{CCA}=1.5V\pm0.1V$ (unless otherwise noted)

Parameter	From	To (Output)		=1.8V 15V		=2.5V .2V		=3.3V .3V	V _{CCE} ±0.	s=5V 5V	Unit
	(Input)	(Output)	Min	Max	Min	Max	Min	Max	Min	Max	
+	А	В	2	15	1.2	11	1.1	10	1	10	10.0
t_{pd}	В	А	1	15	0.9	12	0.5	12	0.3	13	ns
4	OE	А		1		1		1		1	
t _{en}	OE	В		1		1		1		1	μs
t	OE	А	6	30	5.5	28	5.5	25	5.5	23	na
t _{dis}	UE	В	5.5	30	5	25	5	20	5	20	ns
$t_{rA,} t_{fA}$		se and Fall me	1.5	5.0	1.5	5.0	1.5	5.0	1.5	5.0	ns
$t_{rB,}t_{fB}$		se and Fall me	0.9	4.5	0.6	3.5	0.5	3	0.4	2.5	ns
t _{SK(O)}	Channel-t	o-Channel		0.5		0.5		0.5		0.5	ns
Max Data Rate			40		40		40		40		Mbps



Switching Characteristics

Over recommended operating free-air temperature range, $V_{CCA}=1.8V\pm0.15V$ (unless otherwise noted)

Parameter	From	To (Output)	V _{ССВ} = ±0.2	=1.8V 15V		=2.5V .2V	V _{ССВ} : ±0.	=3.3V .3V	V _{CCE} ±0.	3=5V 5V	Unit
	(Input)	(Output)	Min	Max	Min	Max	Min	Max	Min	Max	
+	А	В	1.6	10	1.4	9	1.3	7	1.2	6.5	na
t _{pd}	В	А	1.5	12	1.3	8.5	1	8	0.9	8	ns
+	OE	А		1		1		1		1	
t _{en}	UE	В		1		1		1		1	μs
+	OE	А	6	34	5.5	23	5	20	5	17.6	200
t _{dis}	UE	В	5.5	33	4.5	22	4.2	16.8	4.4	16.3	ns
$t_{rA,} t_{fA}$		se and Fall me	1	4.2	1.1	4.0	1.1	4.0	1.1	4.0	ns
$t_{rB,}t_{fB}$		se and Fall me	0.9	4	0.6	3.2	0.5	2.8	0.4	2.8	ns
t _{SK(O)}	Channel-t	o-Channel		0.5		0.5		0.5		0.5	ns
Max Data Rate			60		60		60		60		Mbps

Switching Characteristics

Over recommended operating free-air temperature range, V_{CCA} =2.5V±0.2V (unless otherwise noted)

Parameter	From			+0 2 V				=3.3V .3V		_B =5V .5V	Unit
	(Input)	(Output)	Min	Max	Min	Max	Min	Max			
+	А	В	1.1	6.5	1	5.2	0.9	5	20		
t _{pd}	В	А	1.2	6.6	1.1	5.1	0.9	4.4	ns		
4	OE	А		1		1		1			
t _{en}	OE	В		1		1		1	μs		
4	OE	А	5.0	23	4.6	15.2	4.6	13			
t _{dis}	OE	В	4.4	22	3.8	16	3.9	13.3	ns		
t_{rA} , t_{fA}	A Port Rise a	nd Fall Time	0.8	3	0.8	3	0.8	3	ns		
t_{rB} , t_{fB}	B Port Rise a	nd Fall Time	0.7	2.7	0.5	2.8	0.4	2.7	ns		
t _{SK(O)}	Channel-to	o-Channel		0.5		0.5		0.5	ns		
Max Data Rate			100		100		100		Mbps		



Switching Characteristics

Over recommended operating free-air temperature range, V_{CCA} =3.3V±0.3V (unless otherwise noted)

Parameter	From	To (Output)	+0.3V			_B =5V 0.5V	Unit
	(Input)	(Output)	Min	Max	Min	Max	
+	А	В	0.9	5	0.8	4	ng
t_{pd}	В	А	1	5.1	0.9	4	ns
4	OE	А		1		1	
t _{en}	OE	В		1		1	μs
4	OE	А	5	15	4	13	
t _{dis}	OE	В	4	16	3.4	13.8	ns
$t_{rA,}t_{fA}$	A Port Rise a	nd Fall Time	0.7	2.5	0.7	2.5	ns
t_{rB} , t_{fB}	B Port Rise a	nd Fall Time	0.5	2.1	0.4	2.8	ns
t _{SK(O)}	Channel-to-Channel			0.5		0.5	ns
Max Data Rate			100		100		Mbps

Operating Characteristics T_A =+25°C

						V _{CCB}				
			5V	1.8V	1.8V	1.8V	2.5V	5V	3.3V to 5V	
1	Parameter	Test Conditions				V _{CCA}				Unit
			1.2V	1.2V	1.5V	1.8V	2.5V	2.5V	3.3V	
			Тур	Тур	Тур	Тур	Тур	Тур	Тур	
C	A-Port Input B-Port Output		9	10	10	10	10	10	10	
C _{pdA}	B-Port Input A-Port Output	C _L =0, f=10MHz,	12	11	11	11	11	11	11	pF
C	A-Port Input B-Port Output	$t_r = t_f = 1ns,$ OE=V _{CCA}	35	28	28	29	3.0	30	30	рг
C _{pdB}	B-Port Input A-Port Output		27	19	19	19	20	21	23	
C	A-Port Input B-Port Output		0.01	0.01	0.01	0.01	0.01	0.01	0.01	
C _{pdA}	B-Port Input A-Port Output	C _L =0, f=10MHz,	0.01	0.01	0.01	0.01	0.01	0.01	0.01	тE
C	A-Port Input B-Port Output	t _r =t _f =1ns, OE=GND	0.01	0.01	0.01	0.01	0.01	0.01	0.03	pF
C _{pdB}	B-Port Input A-Port Output		0.01	0.01	0.01	0.01	0.01	0.01	0.05	



Applications Information

UM3302 ESD protected level translator provides level shifting necessary to allow data transfer in a multi-voltage system. Externally applied voltages, V_{CCA} and V_{CCB} set the logic levels on either side of device. A low voltage signal present on V_{CCA} side of the device appears as a high voltage logic signal on the V_{CCB} side of the device, and vice-versa.

Block Diagram

The UM3302 (block diagram see Figure 1) does not require a direction-control signal to control the direction of data flow from A to B or from B to A. In a dc state, the output drivers of the UM3302 can maintain a high or low, but are designed to be weak, so that they can be overdriven by an external driver when data on the bus starts flowing to the opposite direction.

The output one shot detects rising or falling edges on the A or B ports. During a rising edge, the one shot turns on the PMOS transistors (T1, T3) for a short duration, which speeds up the low-to-high transition. Similarly, during a falling edge, the one shot turns on the NMOS transistors (T2, T4) for a short duration, which speeds up the high-to-low transition.

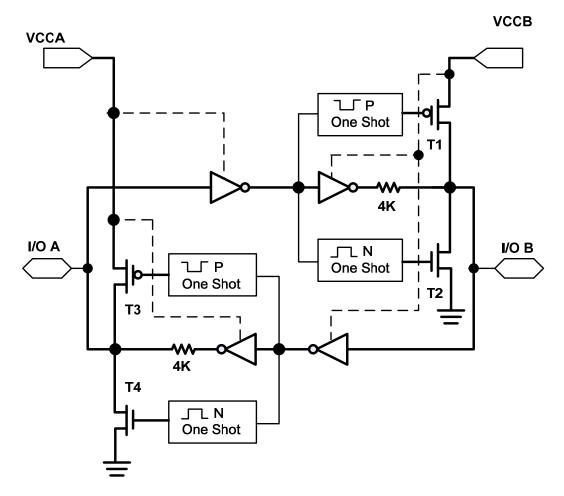
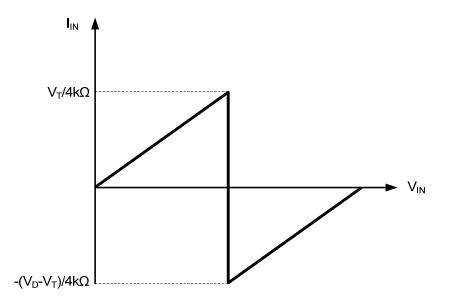


Figure 1 Block Diagram of UM3302 I/O Cell



Input Driver Requirements

Typical I_{IN} vs. V_{IN} characteristics of the UM3302 are shown in Figure 2. For proper operation, the device driving the data I/Os of the UM3302 must have drive strength of at least $\pm 2mA$.



A: V_T is the input threshold voltage of the UM3302 (typical $V_{CCI}/2$). B: V_D is the supply voltage of the external driver.

Figure 2 Typical I_{IN} vs. V_{IN} Curve

Power Up

During operation, ensure that $V_{CCA} \le V_{CCB}$ at all times. During power-up sequencing, $V_{CCA} \ge V_{CCB}$ does not damage the device, so any power supply can be ramped up first. The UM3302 has circuitry that disables all output ports when either V_{CC} is switched off ($V_{CCA/B}=0$ V).

Enable and Disable

The UM3302 has an OE input that is used to disable the device by setting OE=low, which places all I/Os in the high-impedance (Hi-Z) state. The disable time (t_{dis}) indicates the delay between when OE goes low and when the outputs actually get disabled (Hi-Z). The enable time (t_{en}) indicates the amount of time the user must allow for the one-shot circuitry to become operational after OE is taken high.

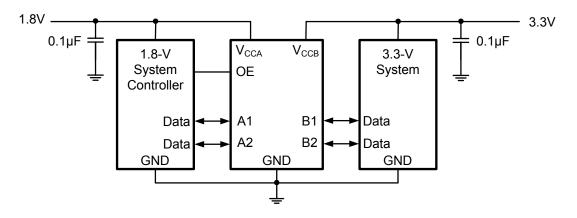
Pull-up or Pull-down Resistors on I/O Lines

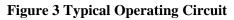
The UM3302 is designed to drive capacitive loads of up to 50pF. The output drivers of the UM3302H have low dc drive strength. If pull-up or pull-down resistors are connected externally to the data I/Os, their values must be kept higher than $50k\Omega$ to ensure that they do not contend with the output drivers of the UM3302.

For the same reason, the UM3302 should not be used in applications such as I^2C or 1-Wire where an open-drain driver is connected on the bidirectional data I/O.

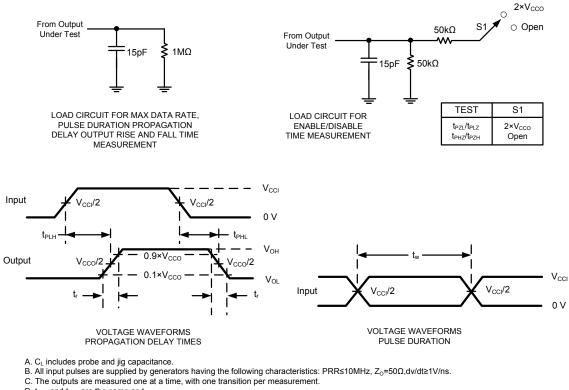


Typical Operating Circuit





Test Circuits



D. t_{PLH} and t_{PHL} are the same as t_{pd} .

E. V_{CCI} is the V_{CC} associated with the input port.

F. V_{CCO} is the V_{CC} associated with the output port.

G. All parameters and waveforms are not applicable to all devices.

Figure 4 Load Circuits and Voltage Waveforms





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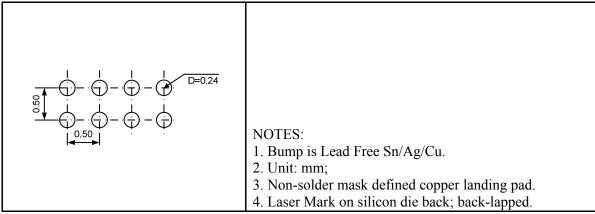
Package Information

UM3302H: CSP8 1.90×0.90

Outline Drawing

. 54 .			DI	MENS	IONS			
	Growbal	MIL	LIMET	ERS		INCHES		
	Symbol - A A1	Min	Тур	Max	Min	Тур	Max	
	Α	-	-	0.68	-	-	0.027	
	A1	0.21	0.231	0.24	0.0083	0.0091	0.0094	
	b	0.27	0.30	0.32	0.011	0.012	0.013	
	С	0.25BS		2	0.010BSC		C	
	D	1.85	1.90	1.95	0.073	0.075	0.077	
Top View Bottom View	D1		1.50BSC	2	(0.059BSC	2	
	Е	0.85	0.90	0.95	0.033	0.035	0.037	
	E1	E1 0.50BSC 0		0.020BSC	2			
Side View E	e		0.50BSC	2		0.020BSC	2	
	L		0.25BSC	2		0.010BSC	2	

Land Pattern



Tape and Reel Orientation



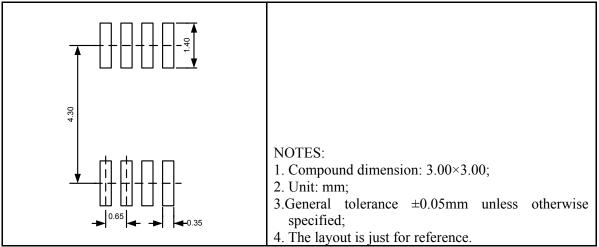




Outline Drawing								
		DIMENSIONS						
		Symbol	MILLIMETERS		INCHES			
			Min	Тур	Max	Min	Тур	Max
		Α	-	-	1.10	-	-	0.043
		A1	0.02	-	0.15	0.0008	-	0.006
		A2	0.75	0.86	0.95	0.030	0.034	0.037
		A3	0.29	0.39	0.49	0.011	0.015	0.019
		b	0.22	-	0.38	0.009	-	0.015
		с	0.08	0.15	0.23	0.003	0.006	0.009
	θ	D	2.90	3.00	3.10	0.114	0.118	0.122
Top View	" End View	Е	2.90	3.00	3.10	0.114	0.118	0.122
		E1	4.70	4.90	5.10	0.185	0.193	0.201
		E3	2.85	2.95	3.05	0.112	0.116	0.120
ີ່ ^{ຮັ້} Side View		e	0.65BSC		0.026BSC			
		L	0.40	0.60	0.80	0.016	0.024	0.031
		θ	0°	-	8°	0°	-	8°

UM3302M8: MSOP8

Land Pattern



Tape and Reel Orientation





GREEN COMPLIANCE

Union Semiconductor is committed to environmental excellence in all aspects of its operations including meeting or exceeding regulatory requirements with respect to the use of hazardous substances. Numerous successful programs have been implemented to reduce the use of hazardous substances and/or emissions.

All Union components are compliant with the RoHS directive, which helps to support customers in their compliance with environmental directives. For more green compliance information, please visit:

http://www.union-ic.com/index.aspx?cat_code=RoHSDeclaration

IMPORTANT NOTICE

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